TOSHIBA Transistor Silicon PNP Triple Diffused Type (PCT process)

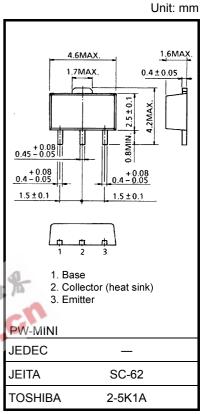
2SA1384

High Voltage Control Applications
Plasma Display, Nixie Tube Driver Applications
Cathode Ray Tube Brightness Control Applications

- High voltage: $V_{CBO} = -300 \text{ V}$, $V_{CEO} = -300 \text{ V}$
- Low saturation voltage: $V_{CE (sat)} = -0.5 \text{ V (max)}$
- Small collector output capacitance: Cob = 6 pF (typ.)
- Complementary to 2SC3515
- Small flat package
- P_C = 1.0 to 2.0 W (mounted on a ceramic substrate)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Collector-base voltage	V _{CBO}	-300	V	
Collector-emitter voltage	V_{CEO}	-300	V	
Emitter-base voltage	V_{EBO}	-8	V	
Collector current	IC	-100	mA	
Base current	I _B	-20	mA	
Collector power dissipation	PC	500		
	P _C (Note 1)	1000	mW	
Junction temperature	Ŧj	150	°C	
Storage temperature range	T _{stg}	-55 to 150	°C	



Weight: 0.05 g (typ.)

- Note 1: 2SA1384 mounted on a ceramic substrate (250 mm² × 0.8 t)
- Note 2: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

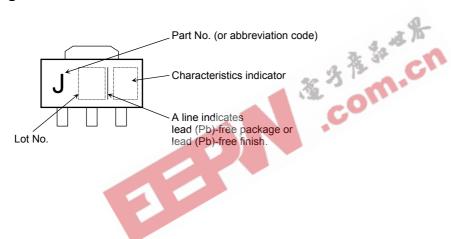
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

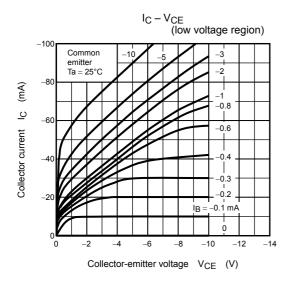
Electrical Characteristics (Ta = 25°C)

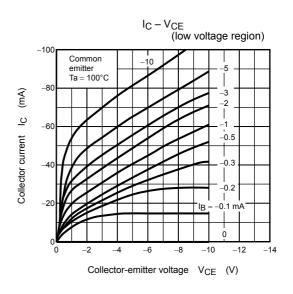
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = -300 \text{ V}, I_{E} = 0$	_	_	-0.1	μΑ
Emitter cut-off current	I _{EBO}	$V_{EB} = -8 \text{ V}, I_{C} = 0$	_	_	-0.1	μΑ
Collector-base breakdown voltage	V (BR) CBO	$I_C = -0.1 \text{ mA}, I_E = 0$	-300	_	-	V
Collector-emitter breakdown voltage	V (BR) CEO	$I_C = -1 \text{ mA}, I_B = 0$	-300	_	-	V
DC current gain	h _{FE (1)} (Note 3)	V _{CE} = -10 V, I _C = -20 mA	30	_	150	
	h _{FE} (2)	V _{CE} = -10 V, I _C = -1 mA	20	_	_	
Collector-emitter saturation voltage	V _{CE} (sat)	$I_C = -20 \text{ mA}, I_B = -2 \text{ mA}$	_	_	-0.5	V
Base-emitter saturation voltage	V _{BE} (sat)	$I_C = -20 \text{ mA}, I_B = -2 \text{ mA}$	_	_	-1.0	V
Transition frequency	f _T	$V_{CE} = -10 \text{ V}, I_{C} = -20 \text{ mA}$	50	70	_	MHz
Collector output capacitance	C _{ob}	V _{CB} = -20 V, I _E = 0, f = 1 MHz	_	6	8	pF

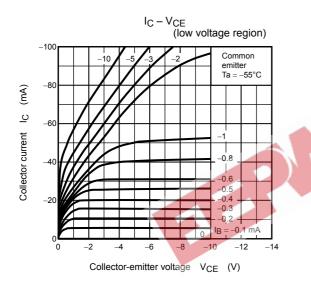
Note 3: $h_{FE\ (1)}$ classification R: 30 to 90, O: 50 to 150

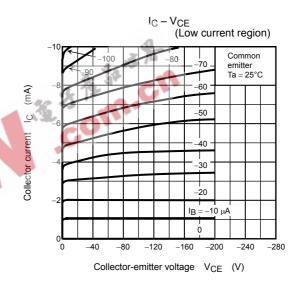
Marking

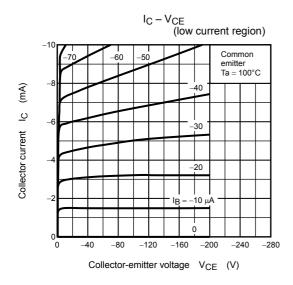


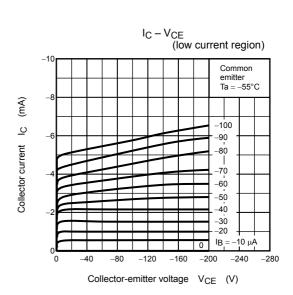


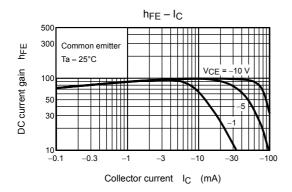


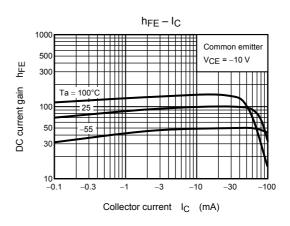


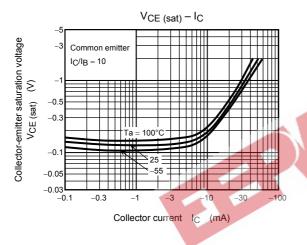


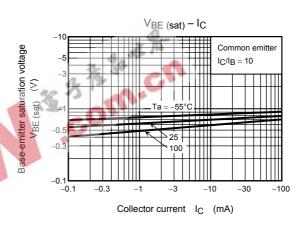


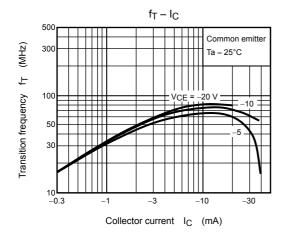


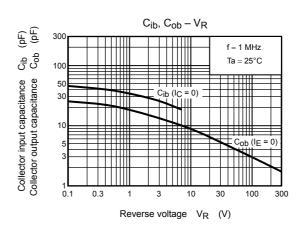


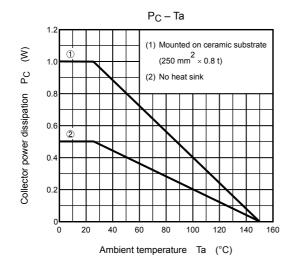


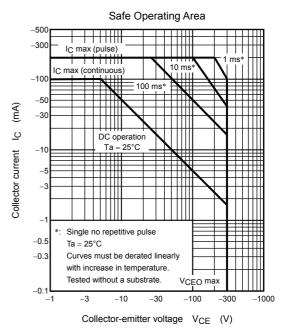














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